NLX3G17

Product Preview

Triple Non-Inverting Schmitt-Trigger Buffer

The NLX3G17 MiniGate™ is an advanced high-speed CMOS triple non-inverting Schmitt-trigger buffer in ultra-small footprint.

The NLX3G17 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

The NLX3G17 can be used to enhance noise immunity or to square up slowly changing waveforms.

Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Low Power Dissipation: I_{CC} = 1 μA (Max) at T_A = 25°C
- 24 mA Balanced Output Source and Sink Capability @ V_{CC} = 3.0 V
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb-Free Devices

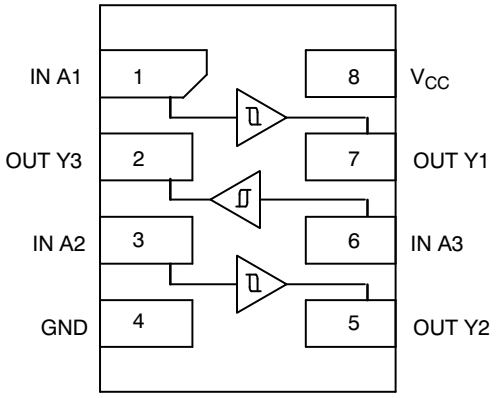

Figure 1. Pinout (Top View)

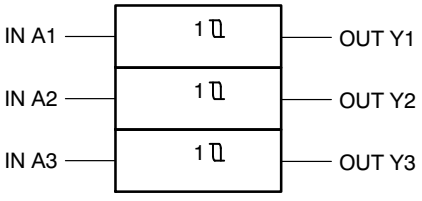

Figure 2. Logic Symbol

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

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MARKING DIAGRAMS

ULLGA8
1.45 x 1.0
CASE 613AA

ULLGA8
1.6 x 1.0
CASE 613AB

ULLGA8
1.95 x 1.0
CASE 613AC

K or AE = Specific Device Code
M = Date Code
▪ = Pb-Free Package

PIN ASSIGNMENT

1	IN A1
2	OUT Y3
3	IN A2
4	GND
5	OUT Y2
6	IN A3
7	OUT Y1
8	V_{CC}

FUNCTION TABLE

A	Y
L H	L H

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		−0.5 to +7.0	V
V_{IN}	DC Input Voltage		−0.5 to +7.0	V
V_{OUT}	DC Output Voltage		−0.5 to +7.0	V
I_{IK}	DC Input Diode Current	V_{IN} < GND	−50	mA
I_{OK}	DC Output Diode Current	V_{OUT} < GND	−50	mA
I_O	DC Output Source/Sink Current		±50	mA
I_{CC}	DC Supply Current Per Supply Pin		±100	mA
I_{GND}	DC Ground Current per Ground Pin		±100	mA
T_{STG}	Storage Temperature Range		−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		150	°C
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating Oxygen	Index: 28 to 34	UL 94 V−0 @ 0.125 in	
$I_{LATCHUP}$	Latchup Performance Above V_{CC} and Below GND at 125 °C (Note 5)		±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm−by−1 inch, 2 ounce copper trace no air flow.
2. Tested to EIA/JESD22−A114−A.
3. Tested to EIA/UESD22−A115−A.
4. Tested to JESD22−C101−A.
5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Positive DC Supply Voltage		1.65	5.5	V
V_{IN}	Digital Input Voltage		0	5.5	V
V_{OUT}	Output Voltage		0	5.5	V
T_A	Operating Free−Air Temperature		−55	+125	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate	V_{CC} = 2.5 V ± 0.2 V V_{CC} = 3.3 V ± 0.3 V V_{CC} = 5.0 V ± 0.5 V	0 0 0	No Limit No Limit No Limit	ns/V

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25 °C			T_A = +85°C		T_A = −55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V_{T+}	Positive Threshold Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.6 1.0 1.2 1.3 1.9 2.2	1.0 1.5 1.7 1.9 2.7 3.3	1.4 1.8 2.0 2.2 3.1 3.6	0.6 1.0 1.2 1.3 1.9 2.2	1.4 1.8 2.0 2.2 3.1 3.6	0.6 1.0 1.2 1.3 1.9 2.2	1.4 1.8 2.0 2.2 3.1 3.6	V
V_{T-}	Negative Threshold Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.2 0.4 0.5 0.6 1.0 1.2	0.5 0.75 0.87 1.0 1.5 1.9	0.8 1.15 1.4 1.5 2.0 2.3	0.2 0.4 0.5 0.6 1.0 1.2	0.8 1.15 1.4 1.5 2.0 2.3	0.2 0.4 0.5 0.6 1.0 1.2	0.8 1.15 1.4 1.5 2.0 2.3	V
V_H	Low−Level Input Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.1 0.25 0.3 0.4 0.6 0.7	0.48 0.75 0.83 0.93 1.2 1.4	0.9 1.1 1.15 1.2 1.5 1.7	0.1 0.25 0.3 0.4 0.6 0.7	0.9 1.1 1.15 1.2 1.5 1.7	0.1 0.25 0.3 0.4 0.6 0.7	0.9 1.1 1.15 1.2 1.5 1.7	V
V_{OH}	High−Level Output Voltage	$V_{IN} \geq V_{T+MAX}$ I_{OH} = −100 μA	1.65 − 5.5	V_{CC} − 0.1	V_{CC}		V_{CC} − 0.1		V_{CC} − 0.1		V
		$V_{IN} \geq V_{T+MAX}$ I_{OH} = −4 mA I_{OH} = −8 mA I_{OH} = −12 mA I_{OH} = −16 mA I_{OH} = −24 mA I_{OH} = −32 mA	 1.65 2.3 2.7 3.0 3.0 4.5	 1.29 1.9 2.2 2.4 2.3 3.8	 1.52 2.1 2.4 2.7 2.5 4.0		 1.29 1.9 2.2 2.4 2.3 3.8		 1.29 1.8 2.1 2.3 2.2 3.7		
V_{OL}	Low−Level Output Voltage	$V_{IN} \leq V_{T-MIN}$ I_{OL} = 100 μA	1.65 − 5.5		0	0.1		0.1		0.1	V
		$V_{IN} \leq V_{T-MIN}$ I_{OH} = 4 mA I_{OH} = 8 mA I_{OH} = 12 mA I_{OH} = 16 mA I_{OH} = 24 mA I_{OH} = 32 mA	 1.65 2.3 2.7 3.0 3.0 4.5	 	 0.08 0.2 0.22 0.28 0.38 0.42	 0.24 0.3 0.4 0.4 0.55 0.55	 	 0.24 0.3 0.4 0.4 0.55 0.55	 	 0.24 0.4 0.5 0.5 0.55 0.55	
I_{IN}	Input Leakage Current	0 ≤ V_{IN} ≤ 5.5 V	0 to 5.5			±0.1		±1.0		±1.0	μA
I_{OFF}	Power−Off Output Leakage Current	V_{OUT} = 5.5 V	0			1.0		10		10	μA
I_{CC}	Quiescent Supply Current	0 ≤ V_{IN} ≤ V_{CC}	5.5			1.0		10		10	μA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ nS)

Symbol	Parameter	V_{CC} (V)	Test Condition	T_A = 25 °C			T_A = +85°C		T_A = −55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay Input A to Output	2.3 to 2.7	R_L = 1 MΩ, C_L = 15 pF	1.8	4.3	7.4	1.8	8.1	1.8	9.1	ns
		3.0 to 3.6	R_L = 1 MΩ, C_L = 15 pF	1.5	3.3	5.0	1.5	5.5	1.5	6.5	
			R_L = 500 Ω, C_L = 50 pF	1.8	4.0	5.0	1.8	6.6	1.8	7.6	
		4.5 to 5.5	R_L = 1 MΩ, C_L = 15 pF	1.0	2.7	4.1	1.0	4.5	1.0	5.5	
			R_L = 500 Ω, C_L = 50 pF	1.2	3.2	4.9	1.2	5.4	1.2	6.4	
C_{IN}	Input Capacitance	5.5	V_{IN} = 0 V or V_{CC}		7.0						pF
C_{PD}	Power Dissipation Capacitance (Note 6)	3.3 5.5	10 MHz V_{IN} = 0 V or V_{CC}		9.0 11						pF

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no−load dynamic power consumption: $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

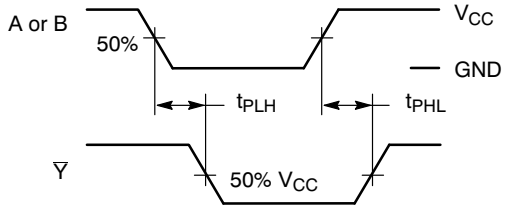
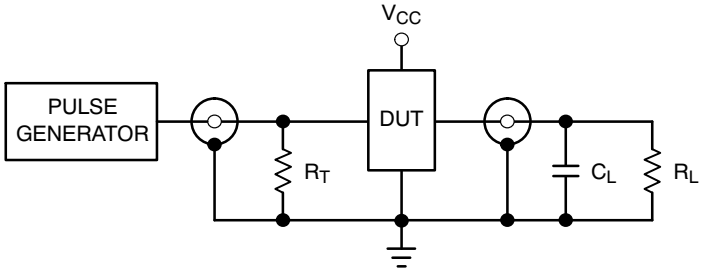


Figure 3. Switching Waveforms



R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

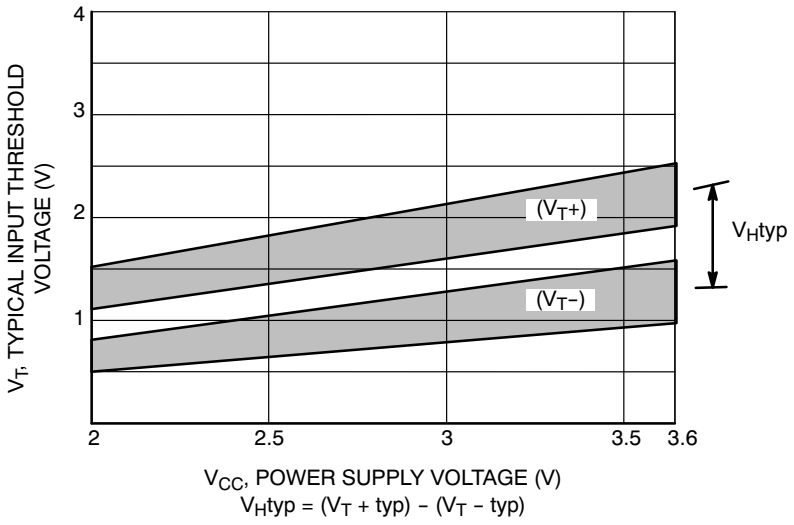
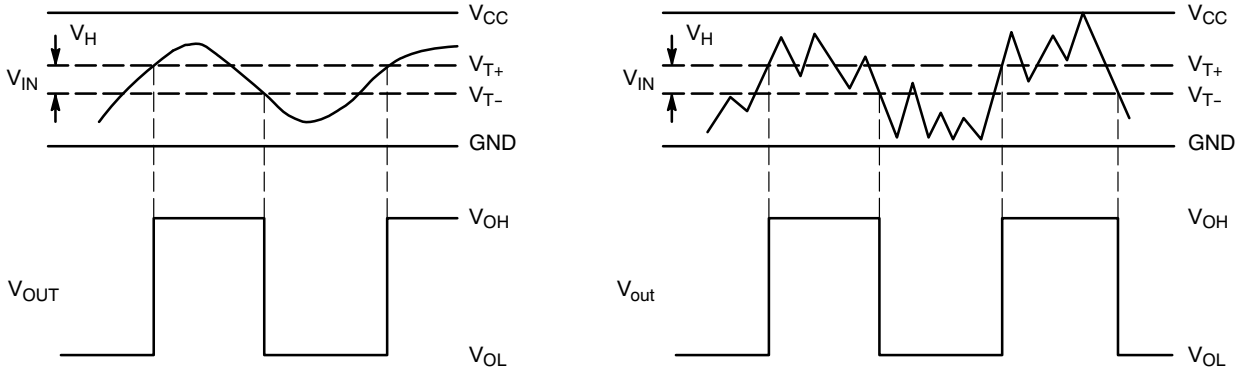


Figure 5. Typical Input Threshold, V_T+, V_T- versus Power Supply Voltage



(a) A Schmitt−Trigger Squares Up Inputs With Slow Rise and Fall Times

(b) A Schmitt−Trigger Offers Maximum Noise Immunity

Figure 6. Typical Schmitt−Trigger Applications

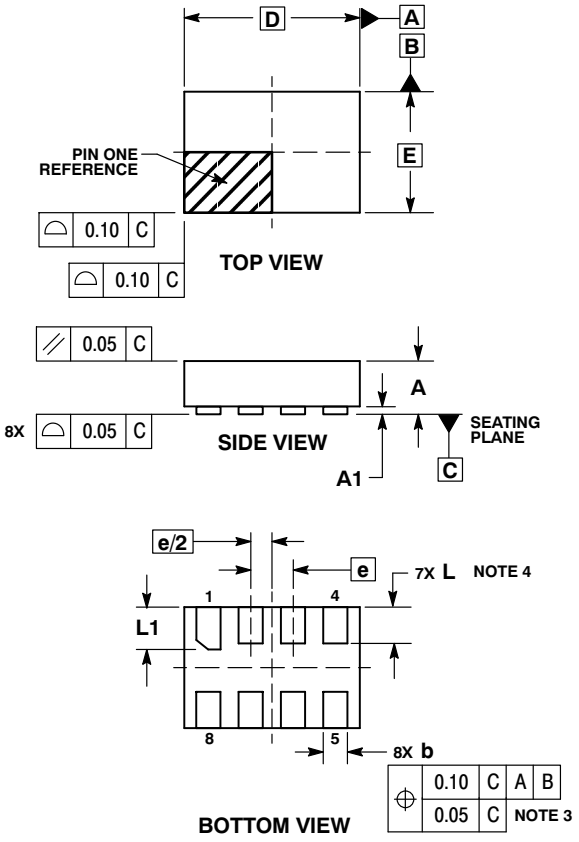
ORDERING INFORMATION

Device	Package	Shipping†
NLX3G17AMX1TCG	ULLGA8, 1.95 x 1.0, 0.5P (Pb−Free)	3000 / Tape & Reel
NLX3G17BMX1TCG	ULLGA8, 1.6 x 1.0, 0.4P (Pb−Free)	3000 / Tape & Reel
NLX3G17CMX1TCG	ULLGA8, 1.45 x 1.0, 0.35P (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

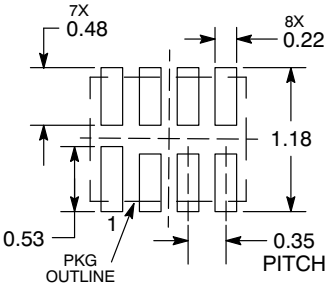
ULLGA8 1.45x1.0, 0.35P
CASE 613AA−01
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.
4. A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.

	MILLIMETERS	
DIM	MIN	MAX
A	---	0.40
A1	0.00	0.05
b	0.15	0.25
D	1.45 BSC	
E	1.00 BSC	
e	0.35 BSC	
L	0.25	0.35
L1	0.30	0.40

MOUNTING FOOTPRINT SOLDERMASK DEFINED*

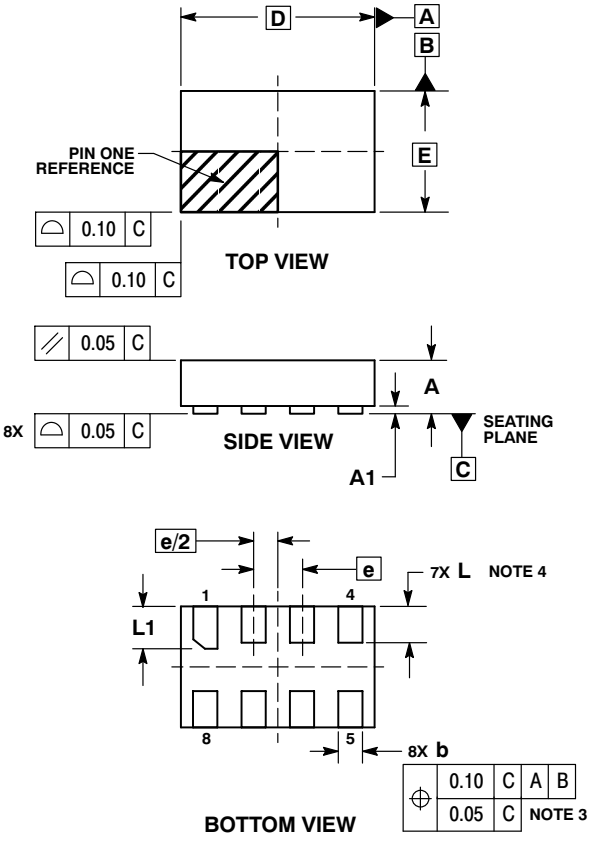


DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

ULLGA8 1.6x1.0, 0.4P
CASE 613AB−01
ISSUE A



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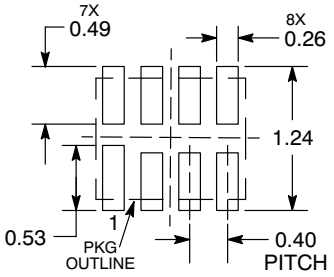
	MILLIMETERS	
DIM	MIN	MAX
A	---	0.40
A1	0.00	0.05
b	0.15	0.25
D	1.60 BSC	
E	1.00 BSC	
e	0.40 BSC	
L	0.25	0.35
L1	0.30	0.40

MOUNTING FOOTPRINT SOLDERMASK DEFINED*



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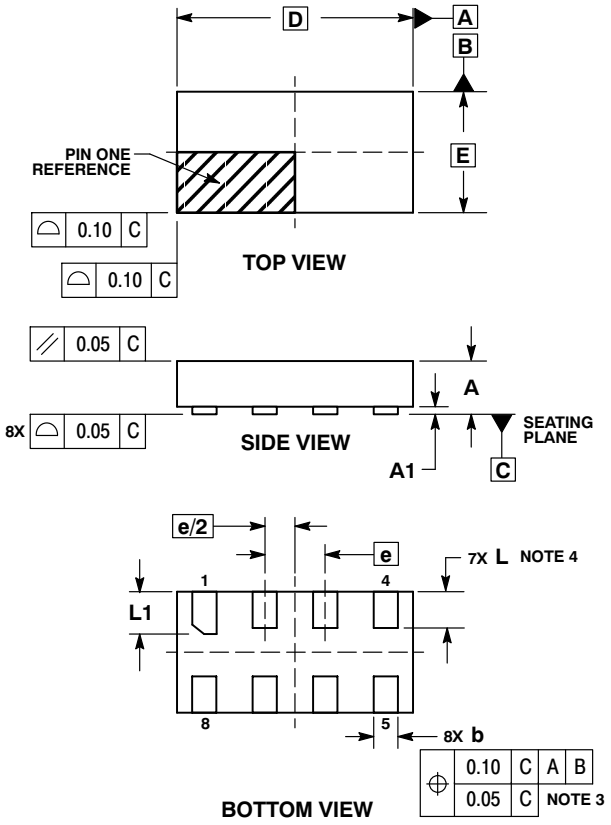
ULLGA8 1.95x1.0, 0.5P
CASE 613AC−01
ISSUE A



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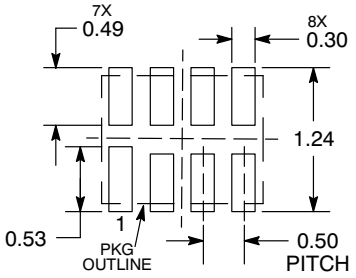
	MILLIMETERS	
DIM	MIN	MAX
A	---	0.40
A1	0.00	0.05
b	0.15	0.25
D	1.95 BSC	
E	1.00 BSC	
e	0.50 BSC	
L	0.25	0.35
L1	0.30	0.40

MOUNTING FOOTPRINT SOLDERMASK DEFINED*



DIMENSIONS: MILLIMETERS

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NLX3G17/D